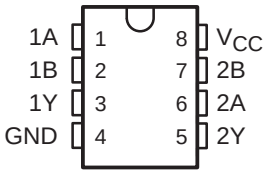
PERIPHERAL DRIVERS FOR HIGH-CURRENT SWITCHING AT VERY HIGH SPEEDS

- **Characterized for Use to 300 mA**
- **High-Voltage Outputs**
- **No Output Latch-Up at 20 V (After Conducting 300 mA)**
- **High-Speed Switching**
- **Circuit Flexibility for Varied Applications**
- **TTL-Compatible Diode-Clamped Inputs**
- **Standard Supply Voltages**
- **Plastic DIP (P) With Copper Lead Frame Provides Cooler Operation and Improved Reliability**
- **Package Options Include Plastic Small-Outline Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs**

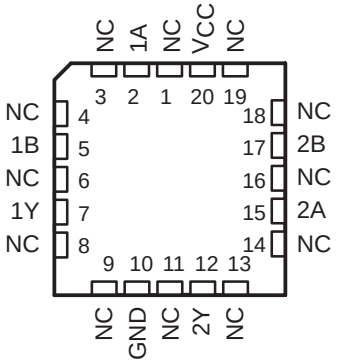
SUMMARY OF DEVICES

DEVICE	LOGIC OF COMPLETE CIRCUIT	PACKAGES
SN55451B	AND	FK, JG
SN55452B	NAND	JG
SN55453B	OR	FK, JG
SN55454B	NOR	JG
SN75451B	AND	D, P
SN75452B	NAND	D, P
SN75453B	OR	D, P
SN75454B	NOR	D, P

SN55451B, SN55452B, SN55453B, SN55454B . . . JG PACKAGE
SN75451B, SN75452B, SN75453B, SN75454B . . . D OR P PACKAGE
(TOP VIEW)



SN55451B, SN55452B
SN55453B, SN55454B . . . FK PACKAGE
(TOP VIEW)



NC – No internal connection

description

The SN55451B through SN55454B and SN75451B through SN75454B are dual peripheral drivers designed for use in systems that employ TTL logic. This family is functionally interchangeable with and replaces the SN75450 family and the SN75450A family devices manufactured previously. The speed of the devices is equal to that of the SN75450 family, and the parts are designed to ensure freedom from latch-up. Diode-clamped inputs simplify circuit design. Typical applications include high-speed logic buffers, power drivers, relay drivers, lamp drivers, MOS drivers, line drivers, and memory drivers.

The SN55451B/SN75451B, SN55452B/SN75452B, SN55453B/SN75453B, and SN55454B/SN75454B are dual peripheral AND, NAND, OR, and NOR drivers, respectively (assuming positive logic), with the output of the logic gates internally connected to the bases of the npn output transistors.

The SN55’ drivers are characterized for operation over the full military range of –55°C to 125°C. The SN75’ drivers are characterized for operation from 0°C to 70°C.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

		SN55'	SN75'	UNIT
Supply voltage, V_{CC} (see Note 1)		7	7	V
Input voltage, V_I		5.5	5.5	V
Inter-emitter voltage (see Note 2)		5.5	5.5	V
Off-state output voltage, V_O		30	30	V
Continuous collector or output current, I_{OK} (see Note 3)		400	400	mA
Peak collector or output current, I_I ($t_W \le 10$ ms, duty cycle $\le 50\%$, see Note 4)		500	500	mA
Continuous total power dissipation		See Dissipation Rating Table		
Operating free-air temperature range, T_A		–55 to 125	0 to 70	°C
Storage temperature range, T_{stg}		–65 to 150	–65 to 150	°C
Case temperature for 60 seconds	FK package	260		°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	JG package	300		°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D or P package		260	°C

NOTES: 1. Voltage values are with respect to network GND, unless otherwise specified.
2. This is the voltage between two emitters of a multiple-emitter transistor.
3. This value applies when the base-emitter resistance (R_{BE}) is equal to or less than 500 Ω.
4. Both halves of these dual circuits may conduct rated current simultaneously; however, power dissipation averaged over a short time interval must fall within the continuous dissipation rating.

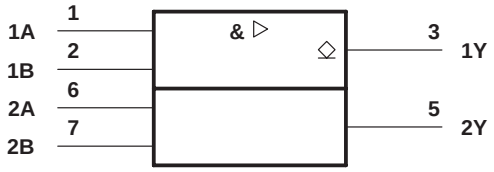
DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25°C$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25°C$	$T_A = 70°C$ POWER RATING	$T_A = 125°C$ POWER RATING
D	725 mW	5.8 mW/°C	464 mW	—
FK	1375 mW	11.0 mW/°C	880 mW	275 mW
JG	1050 mW	8.4 mW/°C	672 mW	210 mW
P	1000 mW	8.0 mW/°C	640 mW	—

recommended operating conditions

	SN55'			SN75'			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
Supply voltage, V_{CC}	4.5	5	5.5	4.75	5	5.25	V
High-level input voltage, V_{IH}	2			2			V
Low-level input voltage, V_{IL}			0.8			0.8	V
Operating free-air temperature, T_A	–55		125	0		70	°C

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

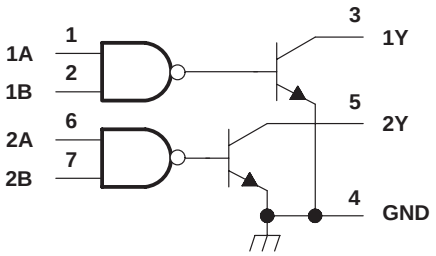
Pin numbers shown are for the D, JG, and P packages.

FUNCTION TABLE (each driver)

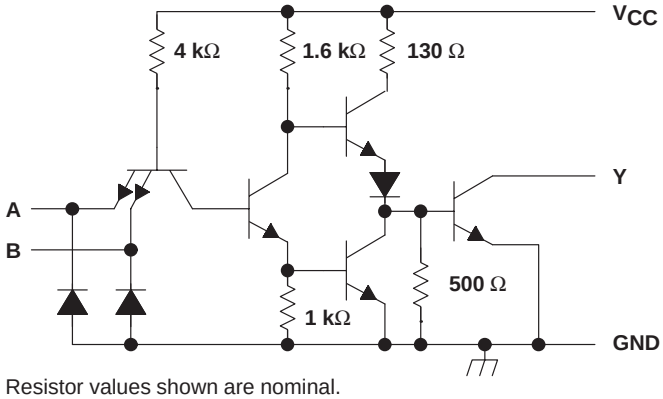
A	B	Y
L	L	L (on state)
L	H	L (on state)
H	L	L (on state)
H	H	H (off state)

positive logic: $Y = AB$ or $\overline{\overline{A}+\overline{B}}$

logic diagram (positive logic)



schematic (each driver)



Resistor values shown are nominal.

electrical characteristics over recommended operating free-air temperature range

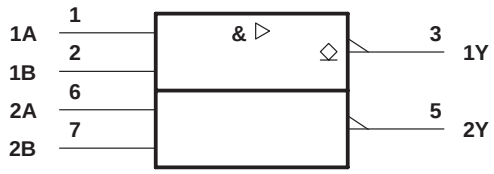
PARAMETER		TEST CONDITIONS‡		SN55451B			SN75451B			UNIT
				MIN	TYP§	MAX	MIN	TYP§	MAX	
V_{IK}	Input clamp voltage	V_{CC} = MIN,	I_I = –12 mA		–1.2	–1.5		–1.2	–1.5	V
V_{OL}	Low-level output voltage	V_{CC} = MIN, I_{OL} = 100 mA	V_{IL} = 0.8 V,		0.25	0.5		0.25	0.4	V
		V_{CC} = MIN, I_{OL} = 300 mA	V_{IL} = 0.8 V,		0.5	0.8		0.5	0.7	
I_{OH}	High-level output current	V_{CC} = MIN, V_{OH} = 30 V	V_{IH} = MIN,			300			100	µA
I_I	Input current at maximum input voltage	V_{CC} = MAX,	V_I = 5.5 V			1			1	mA
I_{IH}	High-level input current	V_{CC} = MAX,	V_I = 2.4 V			40			40	µA
I_{IL}	Low-level input current	V_{CC} = MAX,	V_I = 0.4 V		–1	–1.6		–1	–1.6	mA
I_{CCH}	Supply current, outputs high	V_{CC} = MAX,	V_I = 5 V		7	11		7	11	mA
I_{CCL}	Supply current, outputs low	V_{CC} = MAX,	V_I = 0		52	65		52	65	mA

‡ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
§ All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER			TEST CONDITIONS		MIN	TYP	MAX	UNIT
t_{PLH}	Propagation delay time, low-to-high-level output		$I_O \approx$ 200 mA, R_L = 50 Ω,	C_L = 15 pF, See Figure 1		18	25	ns
t_{PHL}	Propagation delay time, high-to-low-level output					18	25	
t_{TLH}	Transition time, low-to-high-level output					5	8	
t_{THL}	Transition time, high-to-low-level output					7	12	
V_{OH}	High-level output voltage after switching	SN55451B	V_S = 20 V, See Figure 2	$I_O \approx$ 300 mA,	V_S–6.5			mV
		SN75451B			V_S–6.5			

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

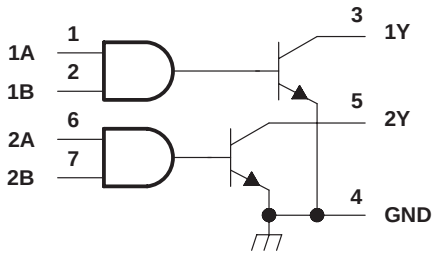
Pin numbers shown are for the D, JG, and P packages.

FUNCTION TABLE (each driver)

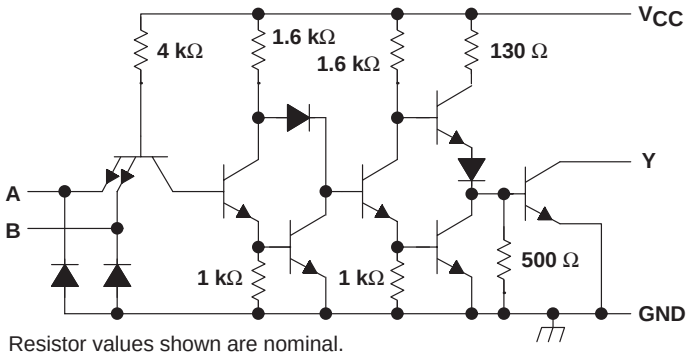
A	B	Y
L	L	H (off state)
L	H	H (off state)
H	L	H (off state)
H	H	L (on state)

positive logic:
$Y = \overline{AB}$ or $\overline{A}+\overline{B}$

logic diagram (positive logic)



schematic (each driver)



Resistor values shown are nominal.

electrical characteristics over recommended operating free-air temperature range

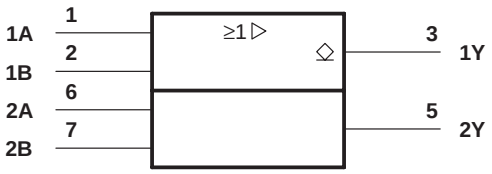
PARAMETER		TEST CONDITIONS‡	SN55452B			SN75452B			UNIT
			MIN	TYP§	MAX	MIN	TYP§	MAX	
V_{IK}	Input clamp voltage	V_{CC} = MIN, I_I = –12 mA		–1.2	–1.5		–1.2	–1.5	V
V_{OL}	Low-level output voltage	V_{CC} = MIN, V_{IH} = MIN, I_{OL} = 100 mA		0.25	0.5		0.25	0.4	V
		V_{CC} = MIN, V_{IH} = MIN, I_{OL} = 300 mA		0.5	0.8		0.5	0.7	
I_{OH}	High-level output current	V_{CC} = MIN, V_{IL} = 0.8 V, V_{OH} = 30 V			300			100	µA
I_I	Input current at maximum input voltage	V_{CC} = MAX, V_I = 5.5 V			1			1	mA
I_{IH}	High-level input current	V_{CC} = MAX, V_I = 2.4 V			40			40	µA
I_{IL}	Low-level input current	V_{CC} = MAX, V_I = 0.4 V		–1.1	–1.6		–1.1	–1.6	mA
I_{CCH}	Supply current, outputs high	V_{CC} = MAX, V_I = 0		11	14		11	14	mA
I_{CCL}	Supply current, outputs low	V_{CC} = MAX, V_I = 5 V		56	71		56	71	mA

‡ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
§ All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics, V_{CC} = 5 V, T_A = 25°C

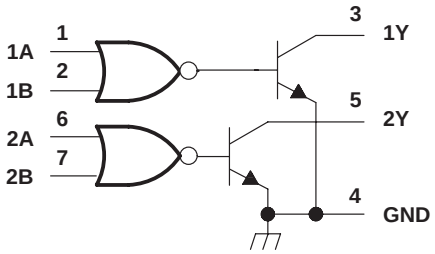
PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH}	Propagation delay time, low-to-high-level output		$I_O \approx$ 200 mA, C_L = 15 pF, R_L = 50 Ω, See Figure 1		26	35	ns
t_{PHL}	Propagation delay time, high-to-low-level output				24	35	
t_{TLH}	Transition time, low-to-high-level output				5	8	
t_{THL}	Transition time, high-to-low-level output				7	12	
V_{OH}	High-level output voltage after switching	SN55452B	V_S = 20 V, $I_O \approx$ 300 mA, See Figure 2	V_S–6.5			mV
		SN75452B		V_S–6.5			

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.
Pin numbers shown are for the D, JG, and P packages.

logic diagram (positive logic)

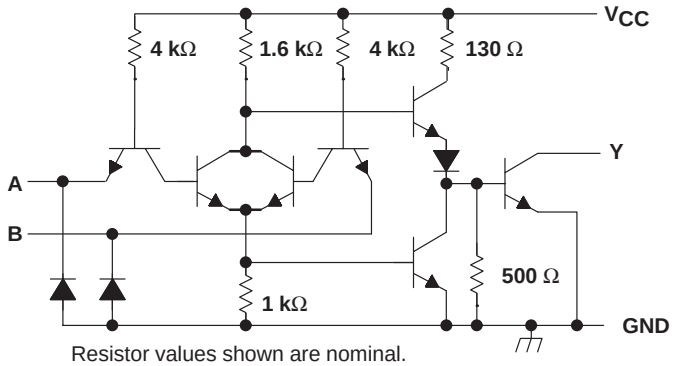


FUNCTION TABLE (each driver)

A	B	Y
L	L	L (on state)
L	H	H (off state)
H	L	H (off state)
H	H	H (off state)

positive logic: $Y = A+B$ or $\overline{\overline{A}\,\overline{B}}$

schematic (each driver)



Resistor values shown are nominal.

electrical characteristics over recommended operating free-air temperature range

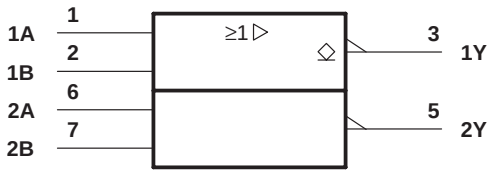
PARAMETER		TEST CONDITIONS‡		SN55453B			SN75453B			UNIT
				MIN	TYP§	MAX	MIN	TYP§	MAX	
V_{IK}	Input clamp voltage	V_{CC} = MIN,	I_I = –12 mA		–1.2	–1.5		–1.2	–1.5	V
V_{OL}	Low-level output voltage	V_{CC} = MIN, I_{OL} = 100 mA	V_{IL} = 0.8 V,		0.25	0.5		0.25	0.4	V
		V_{CC} = MIN, I_{OL} = 300 mA	V_{IL} = 0.8 V,		0.5	0.8		0.5	0.7	
I_{OH}	High-level output current	V_{CC} = MIN, V_{OH} = 30 V	V_{IH} = MIN,			300			100	µA
I_I	Input current at maximum input voltage	V_{CC} = MAX,	V_I = 5.5 V			1			1	mA
I_{IH}	High-level input current	V_{CC} = MAX,	V_I = 2.4 V			40			40	µA
I_{IL}	Low-level input current	V_{CC} = MAX,	V_I = 0.4 V		–1	–1.6		–1	–1.6	mA
I_{CCH}	Supply current, outputs high	V_{CC} = MAX,	V_I = 5 V		8	11		8	11	mA
I_{CCL}	Supply current, outputs low	V_{CC} = MAX,	V_I = 0		54	68		54	68	mA

‡ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
§ All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER			TEST CONDITIONS		MIN	TYP	MAX	UNIT
t_{PLH}	Propagation delay time, low-to-high-level output		$I_O \approx$ 200 mA, R_L = 50 Ω,	C_L = 15 pF, See Figure 1		18	25	ns
t_{PHL}	Propagation delay time, high-to-low-level output					18	25	
t_{TLH}	Transition time, low-to-high-level output					5	8	
t_{THL}	Transition time, high-to-low-level output					7	12	
V_{OH}	High-level output voltage after switching	SN55453B	V_S = 20 V, See Figure 2	$I_O \approx$ 300 mA,	V_S–6.5			mV
		SN75453B			V_S–6.5			

logic symbol†



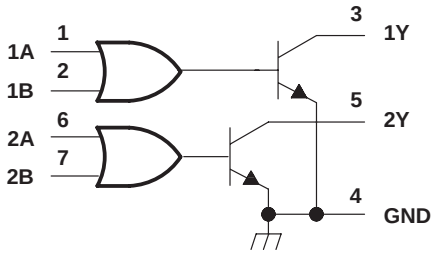
† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.
Pin numbers shown are for the D, JG, and P packages.

FUNCTION TABLE (each driver)

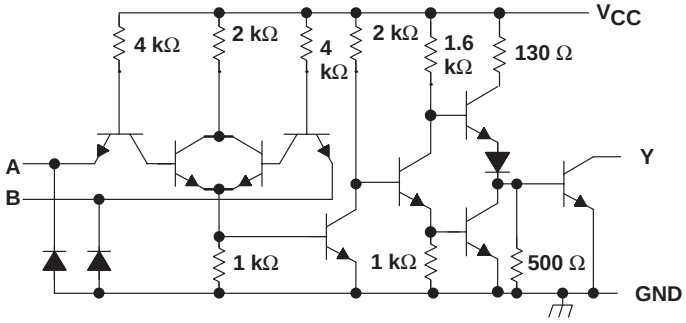
A	B	Y
L	L	H (off state)
L	H	L (on state)
H	L	L (on state)
H	H	L (on state)

positive logic:
$Y = \overline{A+B}$ or $\overline{AB}$

logic diagram (positive logic)



schematic (each driver)



Resistor values shown are nominal.

electrical characteristics over recommended operating free-air temperature range

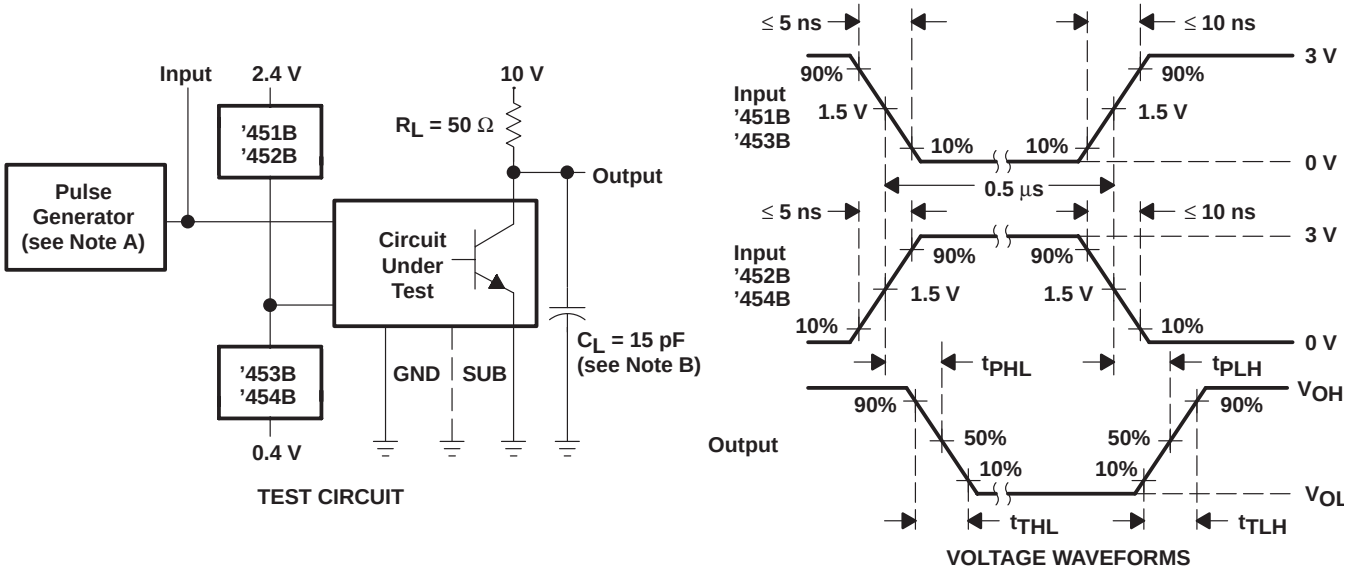
PARAMETER		TEST CONDITIONS‡		SN55454B			SN75454B			UNIT
				MIN	TYP§	MAX	MIN	TYP§	MAX	
V_{IK}	Input clamp voltage	V_{CC} = MIN,	I_I = –12 mA		–1.2	–1.5		–1.2	–1.5	V
V_{OL}	Low-level output voltage	V_{CC} = MIN, I_{OL} = 100 mA	V_{IH} = MIN,		0.25	0.5		0.25	0.4	V
		V_{CC} = MIN, I_{OL} = 300 mA	V_{IH} = MIN,		0.5	0.8		0.5	0.7	
I_{OH}	High-level output current	V_{CC} = MIN, V_{OH} = 30 V	V_{IL} = 0.8 V,			300			100	µA
I_I	Input current at maximum input voltage	V_{CC} = MAX,	V_I = 5.5 V			1			1	mA
I_{IH}	High-level input current	V_{CC} = MAX,	V_I = 2.4 V			40			40	µA
I_{IL}	Low-level input current	V_{CC} = MAX,	V_I = 0.4 V		–1	–1.6		–1	–1.6	mA
I_{CCH}	Supply current, outputs high	V_{CC} = MAX,	V_I = 0		13	17		13	17	mA
I_{CCL}	Supply current, outputs low	V_{CC} = MAX,	V_I = 5 V		61	79		61	79	mA

‡ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
§ All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics, V_{CC} = 5 V, T_A = 25°C

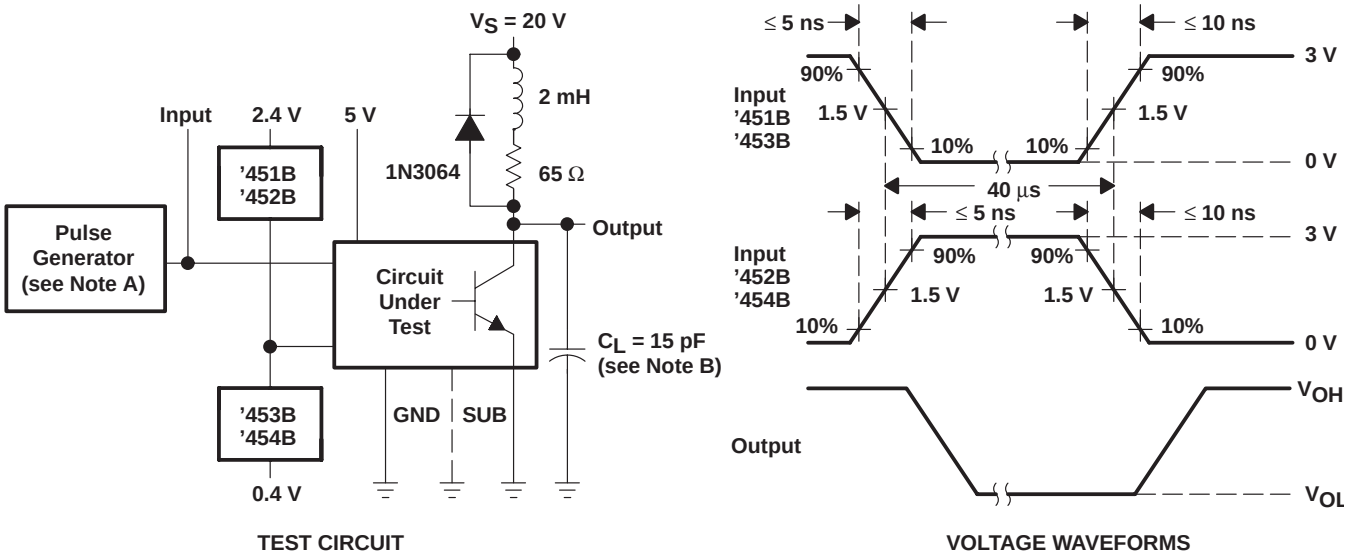
PARAMETER			TEST CONDITIONS		MIN	TYP	MAX	UNIT
t_{PLH}	Propagation delay time, low-to-high-level output		$I_O \approx$ 200 mA, R_L = 50 Ω,	C_L = 15 pF, See Figure 1		27	35	ns
t_{PHL}	Propagation delay time, high-to-low-level output					24	35	
t_{TLH}	Transition time, low-to-high-level output					5	8	
t_{THL}	Transition time, high-to-low-level output					7	12	
V_{OH}	High-level output voltage after switching	SN55454B	V_S = 20 V, See Figure 2	$I_O \approx$ 300 mA,	V_S–6.5			mV
		SN75454B			V_S–6.5			

PARAMETER MEASUREMENT INFORMATION



NOTES: A. The pulse generator has the following characteristics: PRR ≤ 1 MHz, Z_O = 50 Ω.
B. C_L includes probe and jig capacitance.

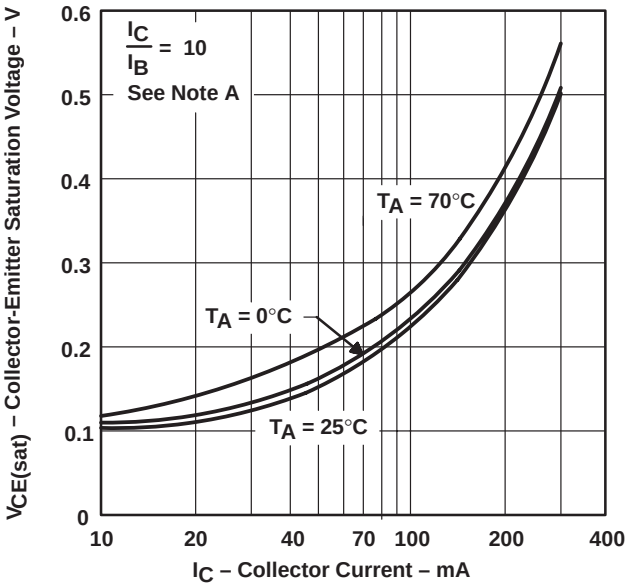
Figure 1. Test Circuit and Voltage Waveforms, Complete Drivers



NOTES: A. The pulse generator has the following characteristics: PRR ≤ 12.5 kHz, Z_O = 50 Ω.
B. C_L includes probe and jig capacitance.

Figure 2. Test Circuit and Voltage Waveforms for Latch-Up Test of Complete Drivers

TYPICAL CHARACTERISTICS



NOTE A: These parameters must be measured using pulse techniques, t_W = 300 µs, duty cycle ≤ 2%.

Figure 3

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